# NSN 5962-01-266-3034

Memory Microcircuit - Page 1 of 1



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# Body Length:

0.930 inches

#### **Body Width:**

0.295 inches

# **Body Height:**

0.200 inches

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## **Features Provided:**

Hermetically sealed and burn in and w/enable and programmable and bipolar

#### **Inclosure Material:**

Ceramic

#### Inclosure Configuration:

Dual-in-line

# **Output Logic Form:**

Transistor-transistor logic

# Input Circuit Pattern:

12 input

# **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

7.0 volts power source

## Time Rating Per Chacteristic:

125.00 nanoseconds propagation delay time, low to high level output and 125.00 nanoseconds propagation delay time, high to low level output

## Memory Device Type:

Rom

## Memory Capacity:

Unknown

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

18 printed circuit

#### Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

#### Fiig:

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